NEC

MOS FIELD EFFECT TRANSISTOR

2SK3353

SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE

DESCRIPTION

The 2SK3353 is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3353	TO-220AB
2SK3353-S	TO-262
2SK3353-Z	TO-220SMD

FEATURES

- Super low on-state resistance:

★ $R_{DS(on)1}$ = 9.5 mΩ MAX. (V_{GS} = 10 V, I_D = 41 A)

★ $R_{DS(on)2}$ = 14 mΩ MAX. (V_{GS} = 4 V, I_D = 41 A)

★ • Low C_{iss}: C_{iss} = 4650 pF TYP.

- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

	Drain to Source Voltage	V_{DSS}	60	V
	Gate to Source Voltage	$V_{GSS(AC)}$	±20	V
	Drain Current (DC)	$I_{D(DC)}$	±82	A
★	Drain Current (pulse) Note1	$I_{D(pulse)}$	±328	A
★	Total Power Dissipation (T_C = 25°C)	P_T	95	W
	Total Power Dissipation (T_A = 25°C)	P_T	1.5	W
	Channel Temperature	T_{ch}	150	°C
	Storage Temperature	T_{stg}	–55 to +150	°C
★	Single Avalanche Current Note2	I_{AS}	45	A
★	Single Avalanche Energy Note2	E_{AS}	202	mJ

Notes 1. PW ≤ 10 μs, Duty cycle ≤ 1 %

★ **2.** Starting T_{ch} = 25 °C, R_G = 25 Ω, V_{GS} = 20 V → 0 V

THERMAL RESISTANCE

★	Channel to Case	Rth(ch-C)	1.32	°C/W
	Channel to Ambient	Rth(ch-A)	83.3	°C/W

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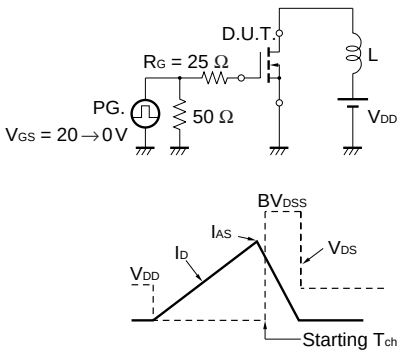
The mark ★ shows major revised points.

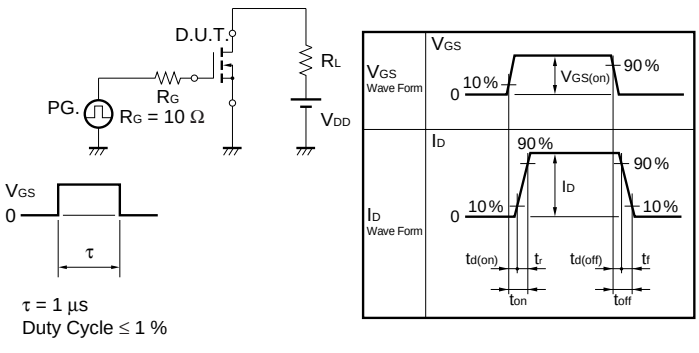
★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	$R_{DS(on)1}$	V_{GS} = 10 V, I_D = 41 A		7.5	9.5	mΩ
	$R_{DS(on)2}$	V_{GS} = 4 V, I_D = 41 A		10.5	14	mΩ
Gate to Source Cut-off Voltage	$V_{GS(off)}$	V_{DS} = 10 V, I_D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	$\|y_{fs}\|$	V_{DS} = 10 V, I_D = 41 A	30	50		S
Drain Leakage Current	I_{DSS}	V_{DS} = 60 V, V_{GS} = 0 V			10	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V			±10	μA
Input Capacitance	C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz		4650		pF
Output Capacitance	C_{oss}			780		pF
Reverse Transfer Capacitance	C_{rss}			380		pF
Turn-on Delay Time	$t_{d(on)}$	I_D = 41 A, $V_{GS(on)}$ = 10 V, V_{DD} = 30 V,		100		ns
Rise Time	t_r	R_G = 10 Ω		1550		ns
Turn-off Delay Time	$t_{d(off)}$			280		ns
Fall Time	t_f			420		ns
Total Gate Charge	Q_G	I_D = 82 A , V_{DD} = 48 V, V_{GS} = 10 V		90		nC
Gate to Source Charge	Q_{GS}			14		nC
Gate to Drain Charge	Q_{GD}			38		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	I_F = 82 A, V_{GS} = 0 V		1.0		V
Reverse Recovery Time	t_{rr}	I_F = 82 A, V_{GS} = 0 V,		60		ns
Reverse Recovery Charge	Q_{rr}	di/dt = 100 A/μs		110		nC

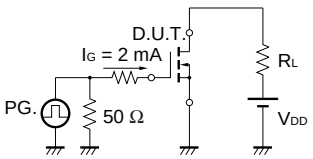
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

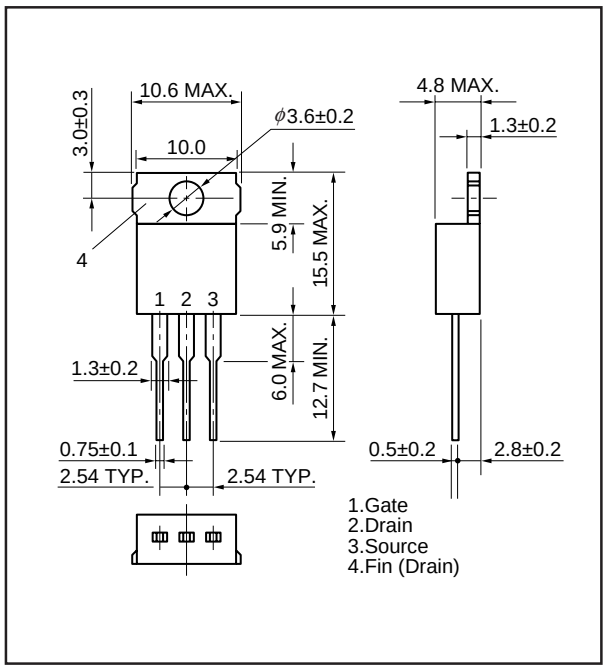


TEST CIRCUIT 3 GATE CHARGE

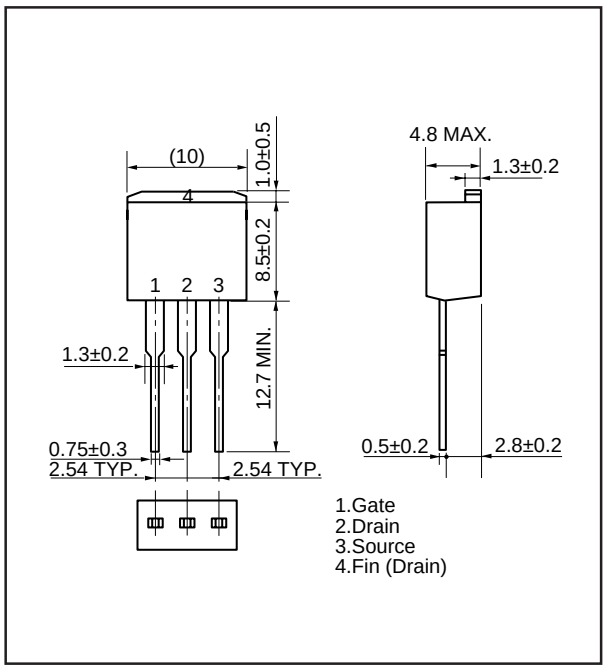


PACKAGE DRAWING (Unit: mm)

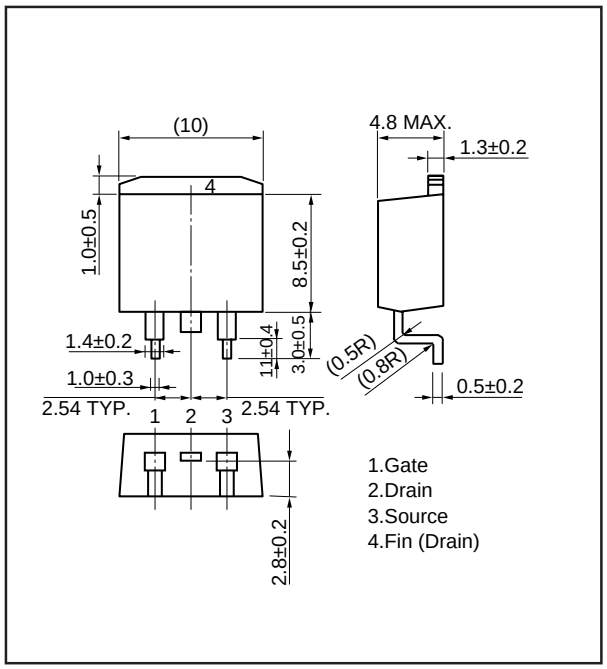
1) TO-220AB (MP-25)



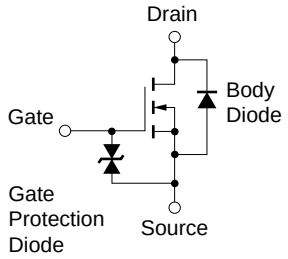
2) TO-262 (MP-25 Fin Cut)



3) TO-220SMD (MP-25Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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